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View Online at https://aerobasegroup.com/nsn/5962-01-111-8382

Body Length: 0.870 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 750.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and hermetically sealed and monolithic and w/enable and selected item **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-2 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Rom **Memory Capacity:** Unknown **Test Data Document:** 53711-5175225 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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